

FEATURES

44 V supply maximum ratings

V_{SS} to V_{DD} analog signal range

Low on resistance (45 Ω max)

Low ΔR_{ON} (5 Ω max)

Low R_{ON} match (4 Ω max)

Low power dissipation

Fast switching times

$t_{ON} < 175$ ns

$t_{OFF} < 145$ ns

Low leakage currents (5 nA max)

Low charge injection (10 pC max)

Break-before-make switching action

APPLICATIONS

Audio and video switching

Battery-powered systems

Test equipment

Communication systems

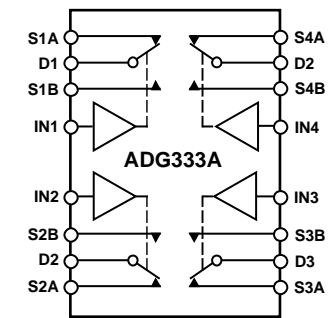
GENERAL DESCRIPTION

The ADG333A is a monolithic CMOS device comprising four independently selectable SPDT switches. It is designed on an LC²MOS process, which provides low power dissipation yet achieves a high switching speed and a low on resistance.

The on resistance profile is very flat over the full analog input range, ensuring good linearity and low distortion when switching audio signals. High switching speed also makes the part suitable for video signal switching. CMOS construction ensures ultralow power dissipation, making the part ideally suited for portable, battery-powered instruments.

When they are on, each switch conducts equally well in both directions and has an input signal range that extends to the power supplies. In the off condition, signal levels up to the supplies are blocked. All switches exhibit break-before-make switching action for use in multiplexer applications. Inherent in the design is low charge inject

FUNCTIONAL BLOCK DIAGRAM



SWITCHES SHOWN FOR A LOGIC 1 INPUT

Figure 1.

01212-001

PRODUCT HIGHLIGHTS

1. Extended signal range.
The ADG333A is fabricated on an enhanced LC²MOS process, giving an increased signal range which extends to the supply rails.
2. Low power dissipation.
3. Low R_{ON} .
4. Single-supply operation.
For applications where the analog signal is unipolar, the ADG333A can be operated from a single rail power supply. The part is fully specified with a single 12 V supply.

Rev. A

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

TABLE OF CONTENTS

| | | | |
|--|---|---|----|
| Specifications..... | 3 | Typical Performance Characteristics | 8 |
| Dual Supply | 3 | Test Circuits..... | 10 |
| Single Supply | 4 | Application Information..... | 11 |
| Absolute Maximum Ratings..... | 5 | ADG333A Supply Voltages | 11 |
| ESD Caution..... | 5 | Power Supply Sequencing | 11 |
| Terminology | 6 | Outline Dimensions | 12 |
| Pin Configurations and Function Descriptions | 7 | Ordering Guide | 12 |

REVISION HISTORY

3/05—Rev. 0 to Rev. A

| | |
|---------------------------------------|-----------|
| Updated Format..... | Universal |
| Changes to Specifications Tables..... | 3 |
| Updated Outline Dimensions | 12 |
| Changes to Ordering Guide | 12 |

10/95—Revision 0: Initial Version

SPECIFICATIONS

DUAL SUPPLY

$V_{DD} = +15\text{ V}$, $V_{SS} = -15\text{ V}$, $GND = 0\text{ V}$, unless otherwise noted.¹

Table 1.

| Parameter | +25°C | -40°C to +85°C | Unit | Test Conditions/Comments |
|--|------------|----------------------|-------------------|---|
| ANALOG SWITCH | | | | |
| Analog Signal Range | | V_{SS} to V_{DD} | V | |
| R_{ON} | 20 | | Ω typ | $V_D = \pm 10\text{ V}$, $I_S = -1\text{ mA}$ |
| | 45 | 45 | Ω max | |
| ΔR_{ON} | | 5 | Ω max | $V_D = \pm 5\text{ V}$, $I_S = -10\text{ mA}$ |
| R_{ON} Match | | 4 | Ω max | $V_D = \pm 10\text{ V}$, $I_S = -10\text{ mA}$ |
| LEAKAGE CURRENTS | | | | |
| Source OFF Leakage I_S (OFF) | ± 0.1 | | nA typ | $V_{DD} = +16.5\text{ V}$, $V_{SS} = -16.5\text{ V}$ |
| | ± 0.25 | ± 3 | nA max | $V_D = \pm 15.5\text{ V}$, $V_S = +15.5\text{ V}$ |
| Channel ON Leakage I_D , I_S (ON) | ± 0.1 | | nA typ | $V_S = V_D = \pm 15.5\text{ V}$ |
| | ± 0.4 | ± 5 | nA max | Figure 15 Figure 16 |
| DIGITAL INPUTS | | | | |
| Input High Voltage, V_{INH} | | 2.4 | V min | |
| Input Low Voltage, V_{INL} | | 0.8 | V max | |
| Input Current | | | | |
| I_{INL} or I_{INH} | | ± 0.005 | μA typ | $V_{IN} = 0\text{ V}$ or V_{DD} |
| | | ± 0.5 | μA max | |
| DYNAMIC CHARACTERISTICS² | | | | |
| t_{ON} | 90 | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; |
| | | 175 | ns max | $V_S = \pm 10\text{ V}$; Figure 17 |
| t_{OFF} | 80 | | ns typ | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; |
| | | 145 | ns max | $V_S = \pm 10\text{ V}$; Figure 17 |
| Break-Before-Make Delay, t_{OPEN} | 10 | | ns min | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; |
| | | | | $V_S = +5\text{ V}$; Figure 18 |
| Charge Injection | 2 | | pC typ | $V_D = 0\text{ V}$, $R_D = 0\ \Omega$, $C_L = 10\text{ nF}$; |
| | 10 | | pC max | $V_{DD} = +15\text{ V}$, $V_{SS} = -15\text{ V}$; Figure 19 |
| OFF Isolation | 72 | | dB typ | $R_L = 75\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; |
| | | | | $V_S = 2.3\text{ V rms}$; Figure 20 |
| Channel-to-Channel Crosstalk | 85 | | dB typ | $R_L = 75\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; |
| | | | | $V_S = 2.3\text{ V rms}$; Figure 21 |
| C_S (OFF) | 7 | | pF typ | |
| C_D , C_S (ON) | 26 | | pF typ | |
| POWER REQUIREMENTS | | | | |
| I_{DD} | 0.05 | | mA typ | Digital inputs = 0 V or 5 V |
| | 0.25 | 0.35 | mA max | |
| I_{SS} | 0.01 | | μA typ | |
| | 1 | 5 | μA max | |
| V_{DD}/V_{SS} | | $\pm 3/\pm 20$ | V min/V max | $ V_{DD} = V_{SS} $ |

¹ Temperature range is as follows: B version: -40°C to $+85^\circ\text{C}$.

² Guaranteed by design; not subject to production test.

ADG333A

SINGLE SUPPLY

$V_{DD} = +12\text{ V}$, $V_{SS} = 0\text{ V} \pm 10\%$, $GND = 0\text{ V}$, unless otherwise noted.¹

Table 2.

| Parameter | +25°C | -40°C to +85°C | Unit | Test Conditions/Comments |
|--|-------------------------|--------------------------|--|--|
| ANALOG SWITCH | | | | |
| Analog Signal Range | | 0 V to V_{DD} | V | |
| RON | 35 | 75 | Ω typ Ω max | $V_D = 1\text{ V}$, 10 V , $I_S = -1\text{ mA}$ |
| LEAKAGE CURRENTS | | | | |
| Source OFF Leakage I_S (OFF) | ± 0.1 ± 0.25 | ± 3 | nA typ nA max | $V_{DD} = 13.2\text{ V}$ $V_D = 12.2\text{ V}/1\text{ V}$, $V_S = 1\text{ V}/12.2\text{ V}$ Figure 15 |
| Channel ON Leakage I_D , I_S (ON) | ± 0.1 ± 0.4 | ± 5 | nA typ nA max | $V_S = V_D = 12.2\text{ V}/1\text{ V}$ Figure 16 |
| DIGITAL INPUTS | | | | |
| Input High Voltage, V_{INH} | | 2.4 | V min | |
| Input Low Voltage, V_{INL} | | 0.8 | V max | |
| Input Current I_{INL} or I_{INH} | | ± 0.005 ± 0.5 | μA typ μA max | $V_{IN} = 0\text{ V}$ or V_{DD} |
| DYNAMIC CHARACTERISTICS² | | | | |
| t_{ON} | 110 | 200 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; $V_S = 8\text{ V}$; Figure 17 |
| t_{OFF} | 100 | 180 | ns typ ns max | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; $V_S = 8\text{ V}$; Figure 17 |
| Break-Before-Make Delay, t_{OPEN} | 10 | | ns min ns min | $R_L = 300\ \Omega$, $C_L = 35\text{ pF}$; $V_S = 5\text{ V}$; Figure 18 |
| Charge Injection | 5 | | pC typ | $V_D = 6\text{ V}$, $R_D = 0\text{ W}$, $C_L = 10\text{ nF}$; $V_{DD} = 12\text{ V}$, $V_{SS} = 0\text{ V}$; Figure 19 |
| OFF Isolation | 72 | | dB typ | $R_L = 75\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; $V_S = 1.15\text{ V rms}$; Figure 20 |
| Channel-to-Channel Crosstalk | 85 | | dB typ | $R_L = 75\ \Omega$, $C_L = 5\text{ pF}$, $f = 1\text{ MHz}$; $V_S = 1.15\text{ V rms}$; Figure 21 |
| C_S (OFF) | 12 | | pF typ | |
| C_D , C_S (ON) | 25 | | pF typ | |
| POWER REQUIREMENTS | | | | |
| I_{DD} | 0.05 0.25 | 0.35 | mA typ mA max | $V_{DD} = 13.5\text{ V}$ Digital inputs = 0 V or 5 V |
| V_{DD} | | $\pm 3/\pm 30$ | V min/V max | |

¹ Temperature range is as follows: B Version: -40°C to +85°C.

² Guaranteed by design; not subject to production test.

ABSOLUTE MAXIMUM RATINGS

$T_A = 25^\circ\text{C}$ unless otherwise noted.

Table 3.

| Parameter | Min |
|---|---|
| V_{DD} to V_{SS} | +44 V |
| V_{DD} to GND | -0.3 V to +30 V |
| V_{SS} to GND | +0.3 V to -30 V |
| Analog, Digital Inputs ¹ | $V_{SS} - 2\text{ V}$ to $V_{DD} + 2\text{ V}$ or 20 mA, whichever occurs first |
| Continuous Current, S or D | 20 mA |
| Peak Current, S or D (Pulsed at 1 ms, 10% Duty Cycle Max) | 40 mA |
| Operating Temperature Range Industrial (B Version) | -40°C to +85°C |
| Storage Temperature Range | -65°C to +125°C |
| Junction Temperature | 150°C |
| θ_{JA} , Thermal Impedance | |
| PDIP Package | 103°C/W |
| SOIC Package | 74°C/W |
| SSOP Package | 130°C/W |
| Lead Temperature, Soldering (10 sec) | 260°C |
| Lead Temperature, Soldering Vapor Phase (60 sec) | 215°C |
| Infrared (15 sec) | 220°C |
| Lead Temperature, Soldering Vapor Phase (60 sec) | 215°C |
| Infrared (15 sec) | 220°C |

¹ Overvoltage at IN, S, or D is clamped by internal diodes. Current should be limited to the maximum ratings given.

Stresses above those listed under Absolute Maximum Ratings may cause permanent damage to the device. This is a stress rating only; functional operation of the device at these or any other conditions above those indicated in the operational section of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Table 4. Truth Table

| Logic | Switch A | Switch B |
|-------|----------|----------|
| 0 | Off | On |
| 1 | On | Off |

ESD CAUTION

ESD (electrostatic discharge) sensitive device. Electrostatic charges as high as 4000 V readily accumulate on the human body and test equipment and can discharge without detection. Although this product features proprietary ESD protection circuitry, permanent damage may occur on devices subjected to high energy electrostatic discharges. Therefore, proper ESD precautions are recommended to avoid performance degradation or loss of functionality.



TERMINOLOGY

R_{ON}

Ohmic resistance between D and S.

ΔR_{ON}

R_{ON} variation due to a change in the analog input voltage with a constant load current.

R_{ON} Match

Difference between the R_{ON} of any two channels.

I_S (OFF)

Source leakage current with the switch off.

I_D (OFF)

Drain leakage current with the switch off.

I_D, I_S (ON)

Channel leakage current with the switch on.

V_D (V_S)

Analog voltage on Terminals D, S.

C_S (OFF)

OFF switch source capacitance.

C_D (OFF)

OFF switch drain capacitance.

C_D, C_S (ON)

ON switch capacitance.

t_{ON}

Delay between applying the digital control input and the output switching on.

t_{OFF}

Delay between applying the digital control input and the output switching off.

t_{OPEN}

Break-before-make delay when switches are configured as a multiplexer.

V_{INL}

Maximum input voltage for Logic 0.

V_{INH}

Minimum input voltage for Logic 1.

I_{INL} (I_{INH})

Input current of the digital input.

Crosstalk

A measure of unwanted signal which is coupled through from one channel to another as a result of parasitic capacitance.

Off Isolation

A measure of unwanted signal coupling through an OFF switch.

Charge Injection

A measure of the glitch impulse transferred from the digital input to the analog output during switching.

PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS

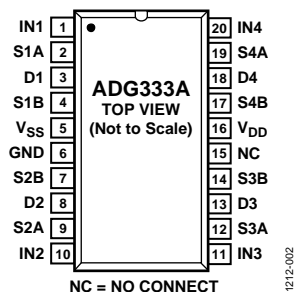


Figure 2. PDIP Pin Configuration

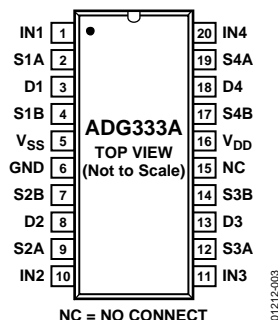


Figure 3. SOIC Pin Configuration

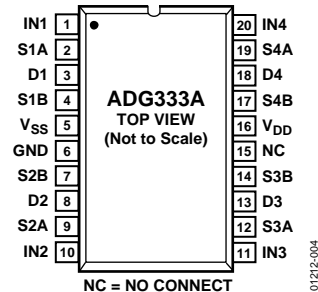


Figure 4. SSOP Pin Configuration

Table 5. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|----------------------------|--|--|
| 1, 10, 11, 20 | IN1, IN2, IN3, IN4 | Logic Control Input. |
| 2, 4, 7, 9, 12, 14, 17, 19 | S1A, S1B, S2B, S2A, S3A, S3B, S4B, S4A | Source Terminal. Can be an input or output. |
| 3, 8, 13, 18 | D1, D2, D3, D4 | Drain Terminal. Can be an input or output. |
| 5 | V _{SS} | Most Negative Power Supply Potential in Dual Supplies. In single-supply applications, it can be connected to ground. |
| 6 | GND | Ground (0 V) Reference. |
| 15 | NC | No Connect. |
| 16 | V _{DD} | Most Positive Power Supply Potential. |

TYPICAL PERFORMANCE CHARACTERISTICS

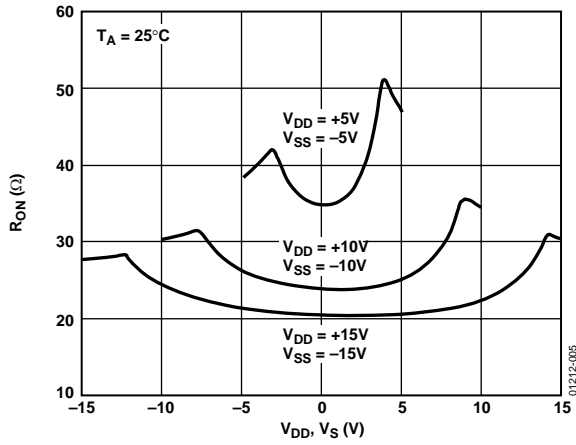


Figure 5. R_{ON} as a Function of V_D (V_S): Dual Supply

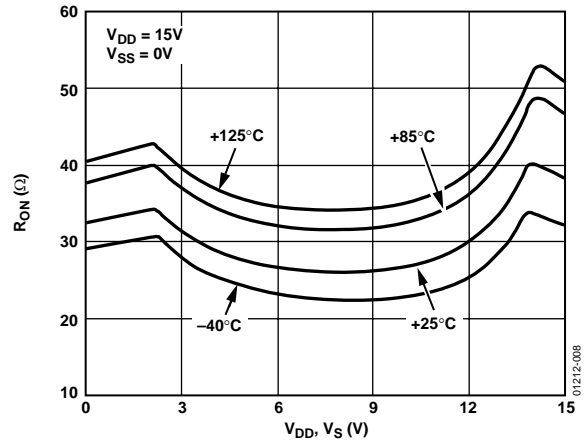


Figure 8. R_{ON} as a Function of V_D (V_S) for Different Temperatures: Single Supply

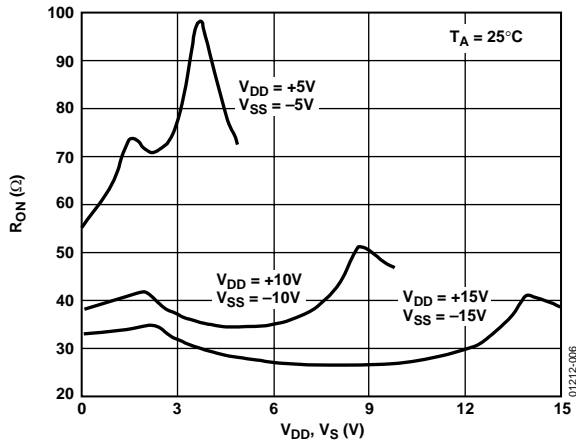


Figure 6. R_{ON} as a Function of V_D (V_S): Single Supply

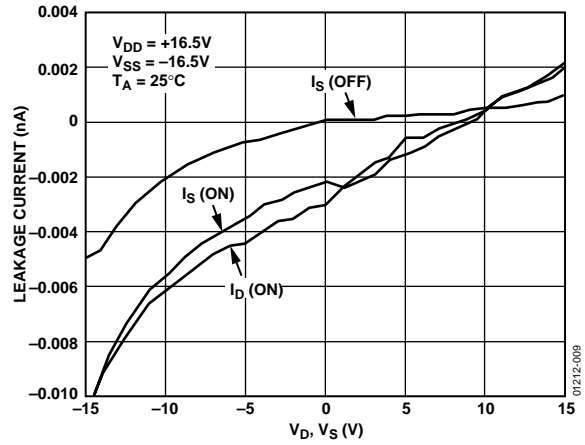


Figure 9. Leakage Currents as a Function of V_D (V_S): Dual Supply

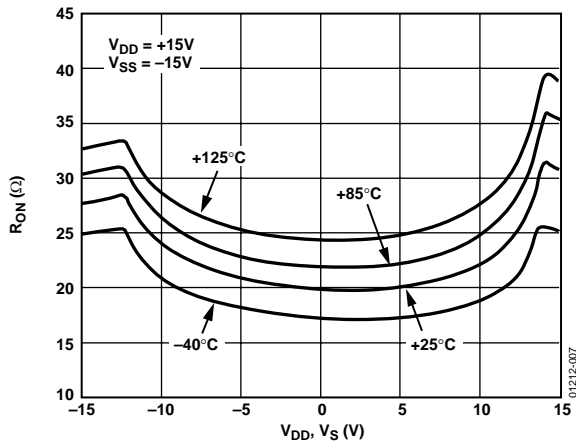


Figure 7. R_{ON} as a Function of V_D (V_S) for Different Temperatures: Dual Supply

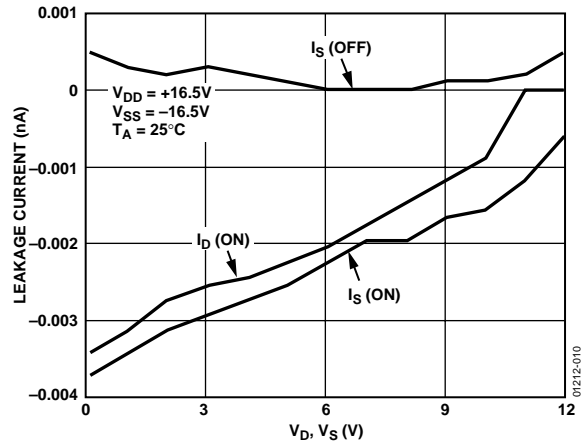


Figure 10. Leakage Currents as a Function of V_D (V_S): Single Supply

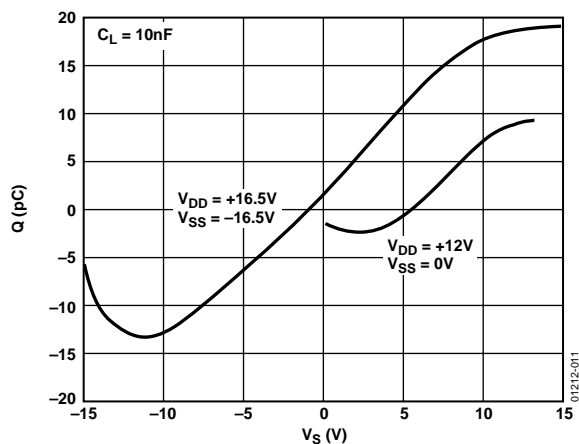


Figure 11. Charge Injection as a Function of V_S

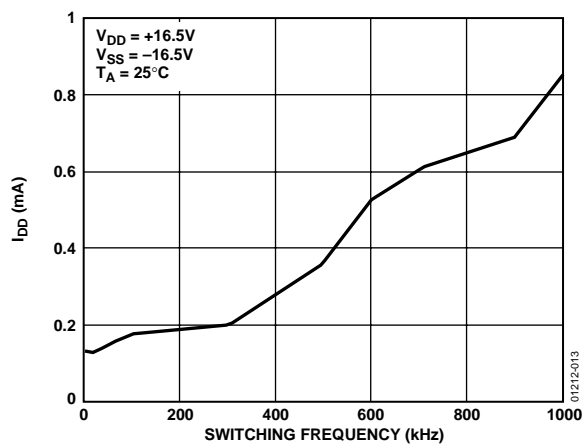


Figure 13. I_{DD} as a Function of Switching Frequency

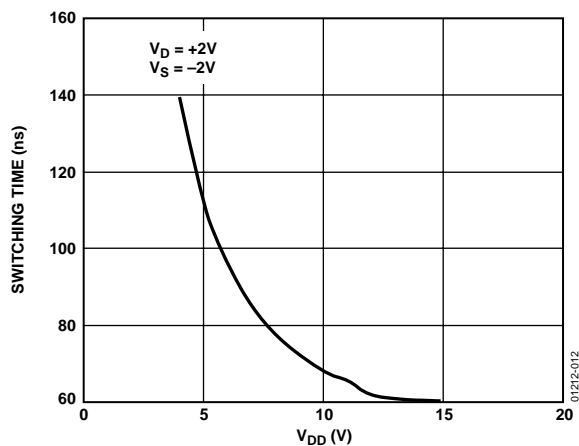


Figure 12. Switching Time as a Function of V_D

TEST CIRCUITS

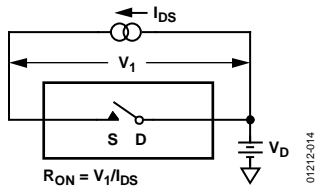


Figure 14. On Resistance

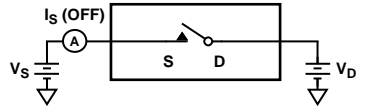


Figure 15. Off Leakage

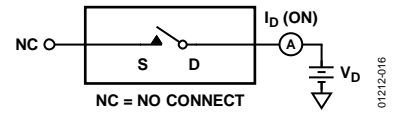


Figure 16. On Leakage

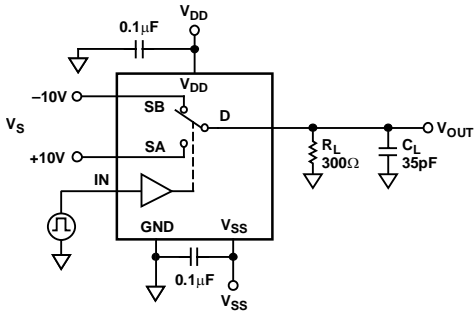


Figure 17. Switching Times

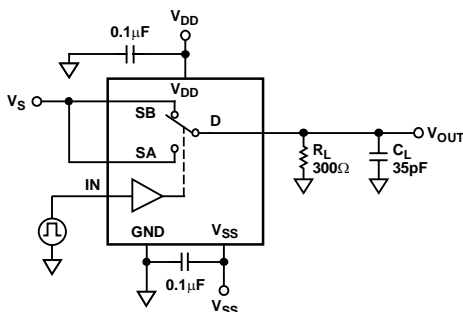
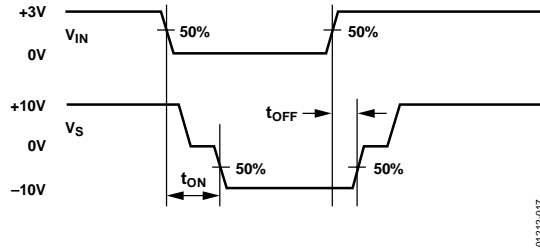


Figure 18. Break-Before-Make Delay, t_{OPEN}

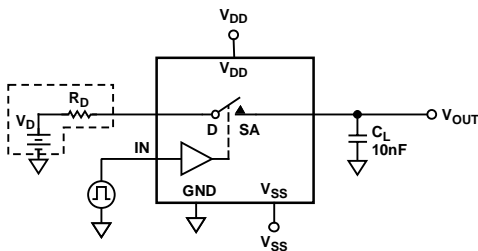
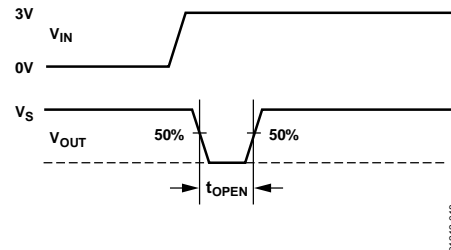


Figure 19. Charge Injection

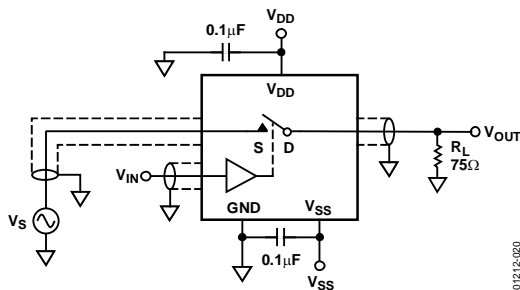
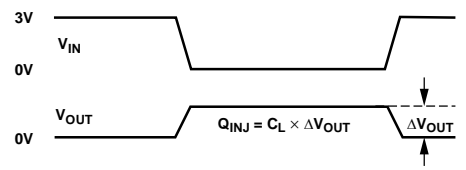


Figure 20. Off Isolation

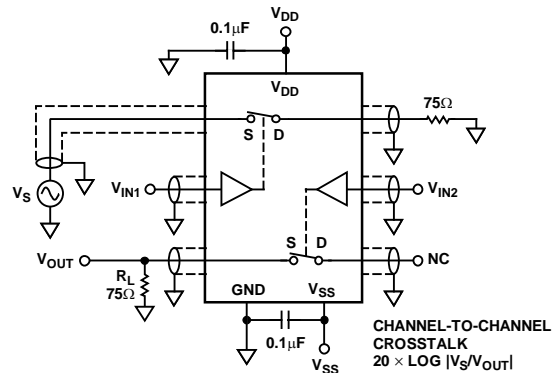


Figure 21. Channel-to-Channel Crosstalk

CHANNEL-TO-CHANNEL
CROSSTALK
 $20 \times \text{LOG} |V_S/V_{OUT}|$

APPLICATION INFORMATION

ADG333A SUPPLY VOLTAGES

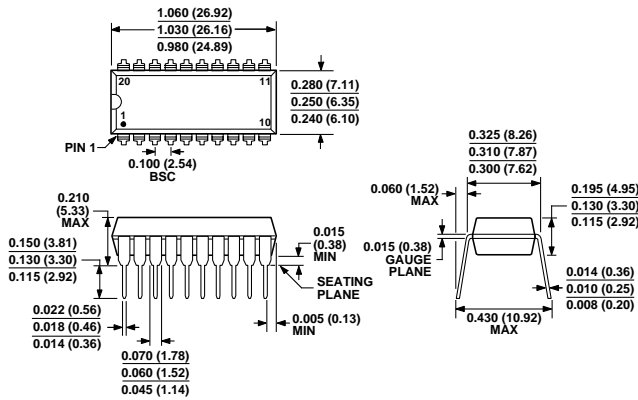
The ADG333A can operate from a dual or signal supply. V_{SS} should be connected to GND when operating with a single supply. When using a dual supply, the ADG333A can also operate with unbalanced supplies; for example $V_{DD} = 20\text{ V}$ and $V_{SS} = -5\text{ V}$. The only restrictions are that V_{DD} to GND must not exceed 30 V, V_{SS} to GND must not drop below -30 V , and V_{DD} to V_{SS} must not exceed +44 V. It is important to remember that the ADG333A supply voltage directly affects the input signal range, the switch on resistance and the switching times of the part. The effects of the power supplies on these characteristics can be clearly seen from the Typical Performance Characteristics curves.

POWER SUPPLY SEQUENCING

When using CMOS devices, care must be taken to ensure correct power-supply sequencing. Incorrect power-supply sequencing can result in the device being subjected to stresses beyond those listed in the Absolute Maximum Ratings. This is also true for the ADG333A. Always turn on V_{DD} first, followed by V_{SS} and the logic signals. An external signal within the maximum specified ratings can then be safely presented to the source or drain of the switch

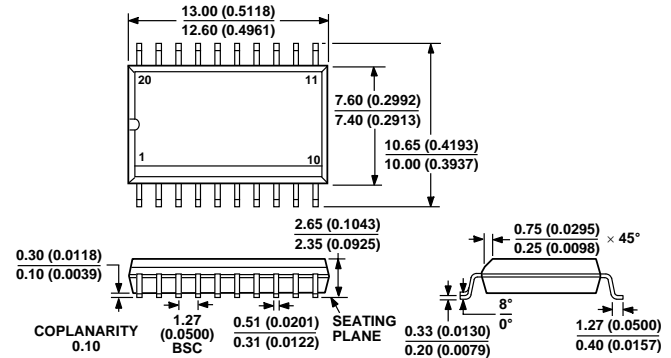
ADG333A

OUTLINE DIMENSIONS



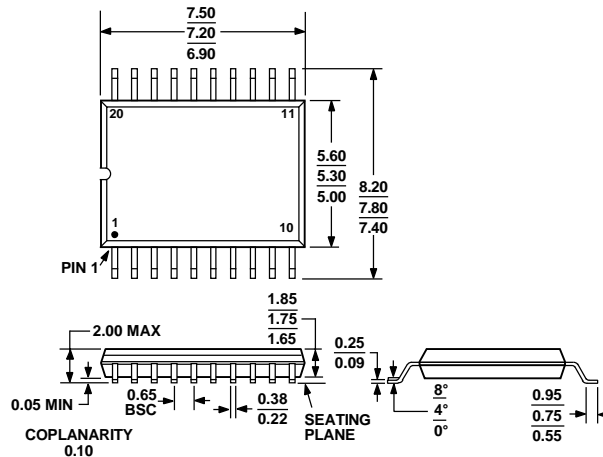
COMPLIANT TO JEDEC STANDARDS MS-001-AD
CONTROLLING DIMENSIONS ARE IN INCHES; MILLIMETER DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF INCH EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN. CORNER LEADS MAY BE CONFIGURED AS WHOLE OR HALF LEADS.

Figure 22. 20-Lead Plastic Dual In-Line Package [PDIP]
Narrow Body (N-20)
Dimensions shown in inches and (millimeters)



COMPLIANT TO JEDEC STANDARDS MS-013AC
CONTROLLING DIMENSIONS ARE IN MILLIMETERS; INCH DIMENSIONS (IN PARENTHESES) ARE ROUNDED-OFF MILLIMETER EQUIVALENTS FOR REFERENCE ONLY AND ARE NOT APPROPRIATE FOR USE IN DESIGN

Figure 23. 20-Lead Standard Small Outline Package [SOIC]
Wide Body (R-20)
Dimensions shown in millimeters and (inches)



COMPLIANT TO JEDEC STANDARDS MO-150AE

Figure 24. 20-Lead Shrink Small Outline Package [SSOP]
(RS-20)
Dimensions shown in millimeters

ORDERING GUIDE

| Model | Temperature Range | Package Description | Package Option |
|-------------------------------|-------------------|---|----------------|
| ADG333ABN | -40°C to +85°C | 20-Lead Plastic Dual In-Line Package (PDIP) | N-20 |
| ADG333ABR | -40°C to +85°C | 20-Lead Standard Small Outline Package (SOIC) | R-20 |
| ADG333ABR-REEL | -40°C to +85°C | 20-Lead Standard Small Outline Package (SOIC) | R-20 |
| ADG333ABRZ ¹ | -40°C to +85°C | 20-Lead Standard Small Outline Package (SOIC) | R-20 |
| ADG333ABRZ-REEL ¹ | -40°C to +85°C | 20-Lead Standard Small Outline Package (SOIC) | R-20 |
| ADG333ABRS | -40°C to +85°C | 20-Lead Shrink Small Outline Package (SSOP) | RS-20 |
| ADG333ABRS-REEL | -40°C to +85°C | 20-Lead Shrink Small Outline Package (SSOP) | RS-20 |
| ADG333ABRSZ ¹ | -40°C to +85°C | 20-Lead Shrink Small Outline Package (SSOP) | RS-20 |
| ADG333ABRSZ-REEL ¹ | -40°C to +85°C | 20-Lead Shrink Small Outline Package (SSOP) | RS-20 |

¹ Z = Pb-free part.

Компания «Океан Электроники» предлагает заключение долгосрочных отношений при поставках импортных электронных компонентов на взаимовыгодных условиях!

Наши преимущества:

- Поставка оригинальных импортных электронных компонентов напрямую с производств Америки, Европы и Азии, а так же с крупнейших складов мира;
- Широкая линейка поставок активных и пассивных импортных электронных компонентов (более 30 млн. наименований);
- Поставка сложных, дефицитных, либо снятых с производства позиций;
- Оперативные сроки поставки под заказ (от 5 рабочих дней);
- Экспресс доставка в любую точку России;
- Помощь Конструкторского Отдела и консультации квалифицированных инженеров;
- Техническая поддержка проекта, помощь в подборе аналогов, поставка прототипов;
- Поставка электронных компонентов под контролем ВП;
- Система менеджмента качества сертифицирована по Международному стандарту ISO 9001;
- При необходимости вся продукция военного и аэрокосмического назначения проходит испытания и сертификацию в лаборатории (по согласованию с заказчиком);
- Поставка специализированных компонентов военного и аэрокосмического уровня качества (Xilinx, Altera, Analog Devices, Intersil, Interpoint, Microsemi, Actel, Aeroflex, Peregrine, VPT, Syfer, Eurofarad, Texas Instruments, MS Kennedy, Miteq, Cobham, E2V, MA-COM, Hittite, Mini-Circuits, General Dynamics и др.);

Компания «Океан Электроники» является официальным дистрибьютором и эксклюзивным представителем в России одного из крупнейших производителей разъемов военного и аэрокосмического назначения «JONHON», а так же официальным дистрибьютором и эксклюзивным представителем в России производителя высокотехнологичных и надежных решений для передачи СВЧ сигналов «FORSTAR».



JONHON

«JONHON» (основан в 1970 г.)

Разъемы специального, военного и аэрокосмического назначения:

(Применяются в военной, авиационной, аэрокосмической, морской, железнодорожной, горно- и нефтедобывающей отраслях промышленности)

«FORSTAR» (основан в 1998 г.)

ВЧ соединители, коаксиальные кабели,
кабельные сборки и микроволновые компоненты:

(Применяются в телекоммуникациях гражданского и специального назначения, в средствах связи, РЛС, а так же военной, авиационной и аэрокосмической отраслях промышленности).



Телефон: 8 (812) 309-75-97 (многоканальный)

Факс: 8 (812) 320-03-32

Электронная почта: ocean@oceanchips.ru

Web: <http://oceanchips.ru/>

Адрес: 198099, г. Санкт-Петербург, ул. Калинина, д. 2, корп. 4, лит. А